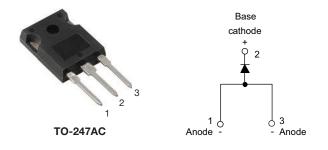


Vishay Semiconductors

High Voltage, Input Rectifier Diode, 80 A



PRODUCT SUMMARY							
Package	TO-247AC						
I _{F(AV)}	80 A						
V _R	800 V to 1200 V						
V _F at I _F	1.17 V						
I _{FSM}	1500 A						
T _J max.	150 °C						
Diode variation	Single die						

FEATURES

- Very low forward voltage drop
- 150 °C max. operating junction temperature
- Glass passivated pellet chip junction
- \bullet Designed and qualified according to JEDEC $^{\textcircled{B}}\text{-}JESD$ 47

RoHS COMPLIANT HALOGEN FREE Available

• Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

DESCRIPTION

High voltage rectifiers optimized for very low forward voltage drop with moderate leakage.

These devices are intended for use in main rectification (single or three phase bridge).

MAJOR RATINGS AND CHARACTERISTICS									
SYMBOL	CHARACTERISTICS	VALUES	UNITS						
I _{F(AV)}	Sinusoidal waveform	80	A						
V _{RRM}	Range	800/1200	V						
I _{FSM}		1500	A						
V _F	80 A, T _J = 25 °C	1.17	V						
TJ		-40 to +150	°C						

VOLTAGE RATINGS								
PART NUMBER	V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA					
VS-80APS08PbF, VS-80APS08-M3	800	900	1.5					
VS-80APS12PbF, VS-80APS12-M3	1200	1300	1.5					

ABSOLUTE MAXIMUM RATINGS										
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS						
Maximum average forward current	I _{F(AV)}	$T_C = 100 \ ^{\circ}C$, 180° conduction half sine wave	80							
Maximum peak one cycle	1	10 ms sine pulse, rated V_{RRM} applied	1450	A						
non-repetitive surge current	IFSM	10 ms sine pulse, no voltage reapplied	1500							
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V_{RRM} applied	10 500	A ² s						
Maximum intro rusing	1-1	10 ms sine pulse, no voltage reapplied	14 000							
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	140 000	A²√s						

Revision: 11-Feb-16

Document Number: 93794

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ELECTRICAL SPECIFICATIONS									
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS				
Maximum forward voltage drop	V _{FM}	80 A, T _J = 25 °C		1.17	V				
Forward slope resistance	r _t	T.I = 150 °C		3.17	mΩ				
Threshold voltage	V _{F(TO)}	1j = 150 C		0.73	V				
Maximum reverse leakage current	I _{RM}	$T_J = 25 ^{\circ}C$		0.1	mA				
waximum reverse reakage current		T _J = 150 °C	$V_R = Rated V_{RRM}$	1.5	ША				

THERMAL - MECHANICAL SPECIFICATIONS								
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum junction and storag temperature range	e	T _J , T _{Stg}		-40 to 150	°C			
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	0.35				
Maximum thermal resistance, junction to ambient		R _{thJA}		40	°C/W			
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, flat, smooth and greased	0.2]			
Approvimate weight				6	g			
Approximate weight				0.21	oz.			
Mounting torque	minimum			6 (5)	kgf ⋅ cm			
Mounting torque	maximum			12 (10)	(lbf · in)			
Marking device				80APS08				
			Case style TO-247AC (JEDEC)		PS12			

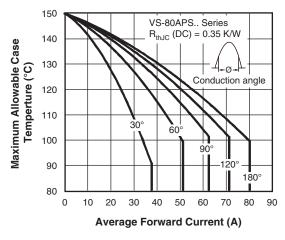


Fig. 1 - Current Rating Characteristics

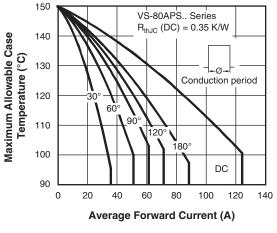


Fig. 2 - Current Rating Characteristics



VS-80APS..PbF Series, VS-80APS..-M3 Series

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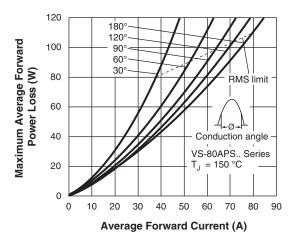


Fig. 3 - Forward Power Loss Characteristics

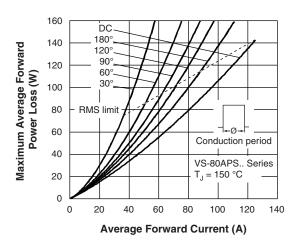
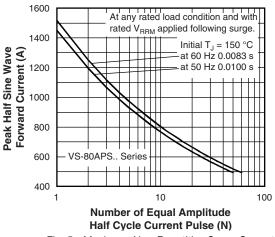


Fig. 4 - Forward Power Loss Characteristics





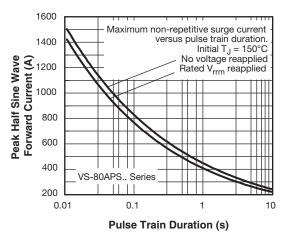
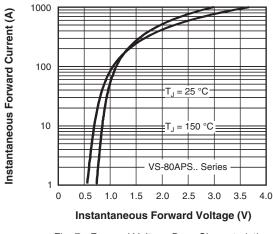
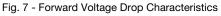


Fig. 6 - Maximum Non-Repetitive Surge Current





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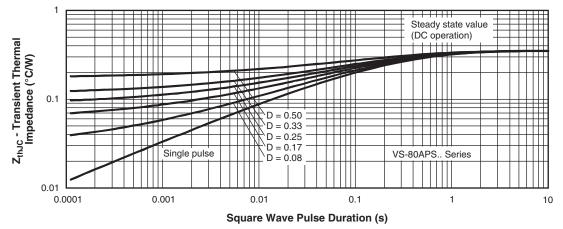


Fig. 8 - Thermal Impedance ZthJC Characteristics

ORDERING INFORMATION TABLE

Device code	VS-	80	Α	Р	s	12	PbF
		(2)	(3)	(4)	(5)	(6)	
	1 - 2 - 3 -	Curr Circ	rent ratii uit confi	iiconduc ng (80 = guratior liode, 3	80 A) 1:	duct	
	4	Pac	kage: TO-247				
	5		e of silic standar	on: d recove	erv recti	fier –	
	6 7	· Volt - Env	age ratii ironmen				08 = 80 12 = 120 mpliant
		-M3	= halog	en-free,	RoHS-	complia	nt, and

ORDERING INFORMATION (Example)									
PREFERRED P/N	QUANTITY PER T/R	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION						
VS-80APS08PbF	25	500	Antistatic plastic tubes						
VS-80APS08-M3	25	500	Antistatic plastic tubes						
VS-80APS12PbF	25	500	Antistatic plastic tubes						
VS-80APS12-M3	25	500	Antistatic plastic tubes						

LINKS TO RELATED DOCUMENTS								
Dimensions		www.vishay.com/doc?95542						
Part marking information	TO-247AC modified PbF	www.vishay.com/doc?95226						
	TO-247AC modified -M3	www.vishay.com/doc?95007						
SPICE model		www.vishay.com/doc?95550						

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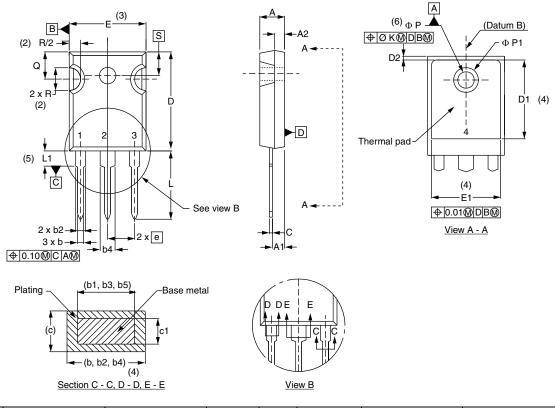
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TO-247AC - 50 mils L/F

DIMENSIONS in millimeters and inches



SYMBOL	MILLIMETERS		INC	HES	NOTES	NOTES		MILLIN	IETERS	INC	HES	NOTES
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES		SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209			D2	0.51	1.35	0.020	0.053	
A1	2.21	2.59	0.087	0.102			E	15.29	15.87	0.602	0.625	3
A2	1.17	1.37	0.046	0.054			E1	13.46	-	0.53	-	
b	0.99	1.40	0.039	0.055			е	5.46	BSC	0.215	BSC	
b1	0.99	1.35	0.039	0.053			ØК	0.2	254	0.0)10	
b2	1.65	2.39	0.065	0.094			L	14.20	16.10	0.559	0.634	
b3	1.65	2.34	0.065	0.092			L1	3.71	4.29	0.146	0.169	
b4	2.59	3.43	0.102	0.135			ØР	3.56	3.66	0.14	0.144	
b5	2.59	3.38	0.102	0.133			Ø P1	-	7.39	-	0.291	
С	0.38	0.89	0.015	0.035			Q	5.31	5.69	0.209	0.224	
c1	0.38	0.84	0.015	0.033			R	4.52	5.49	0.178	0.216	
D	19.71	20.70	0.776	0.815	3		S	5.51	BSC	0.217	BSC	
D1	13.08	-	0.515	-	4							

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

(3) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

⁽⁴⁾ Thermal pad contour optional with dimensions D1 and E1

⁽⁵⁾ Lead finish uncontrolled in L1

⁽⁶⁾ Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension c and Q

Revision: 20-Apr-17

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